

RAIL TO RAIL CMOS DUAL OPERATIONAL AMPLIFIER (WITH **STANDBY** POSITION)

- RAIL TO RAIL INPUT AND OUTPUT VOLTAGE RANGES
- **STANDBY POSITION** : REDUCED CONSUMPTION (0.5µA) AND HIGH IMPEDANCE OUTPUTS
- SINGLE (OR DUAL) SUPPLY OPERATION FROM **2.7V TO 16V**
- EXTREMELY LOW INPUT BIAS CURRENT : **1pA typ**
- LOW INPUT OFFSET VOLTAGE : **5mV max.**
- SPECIFIED FOR **600Ω** AND **100Ω** LOADS
- LOW SUPPLY CURRENT : 200µA/Ampli ($V_{CC} = 3V$)
- **SPICE MACROMODEL** INCLUDED IN THIS-SPECIFICATION

DESCRIPTION

The TS902 is a RAIL TO RAIL CMOS dual operational amplifier designed to operate with a single or dual supply voltage.

The input voltage range V_{icm} includes the two supply rails V_{CC}^+ and V_{CC}^- .

The output reaches :

- $V_{CC}^- + 50mV$ $V_{CC}^+ - 50mV$ with $R_L = 10k\Omega$
- $V_{CC}^- + 350mV$ $V_{CC}^+ - 400mV$ with $R_L = 600\Omega$

This product offers a broad supply voltage operating range from 2.7V to 16V and a supply current of only 200µA/amp. ($V_{CC} = 3V$).

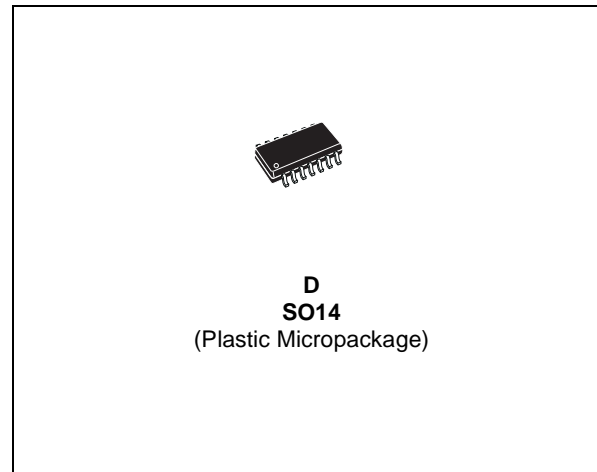
Source and sink output current capability is typically 40mA (at $V_{CC} = 3V$), fixed by an internal limitation circuit.

The TS902 can be put on **STANDBY** position (only 0.5µA and high impedance outputs).

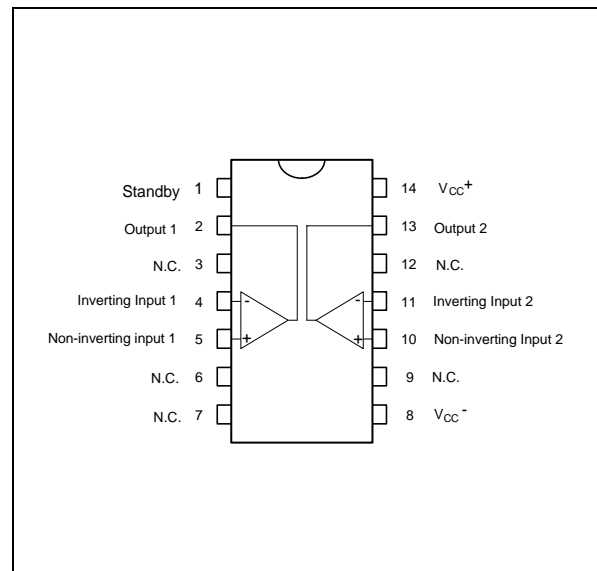
ORDER CODE

Part Number	Temperature Range	Package
		D
TS902I	-40, +125°C	•

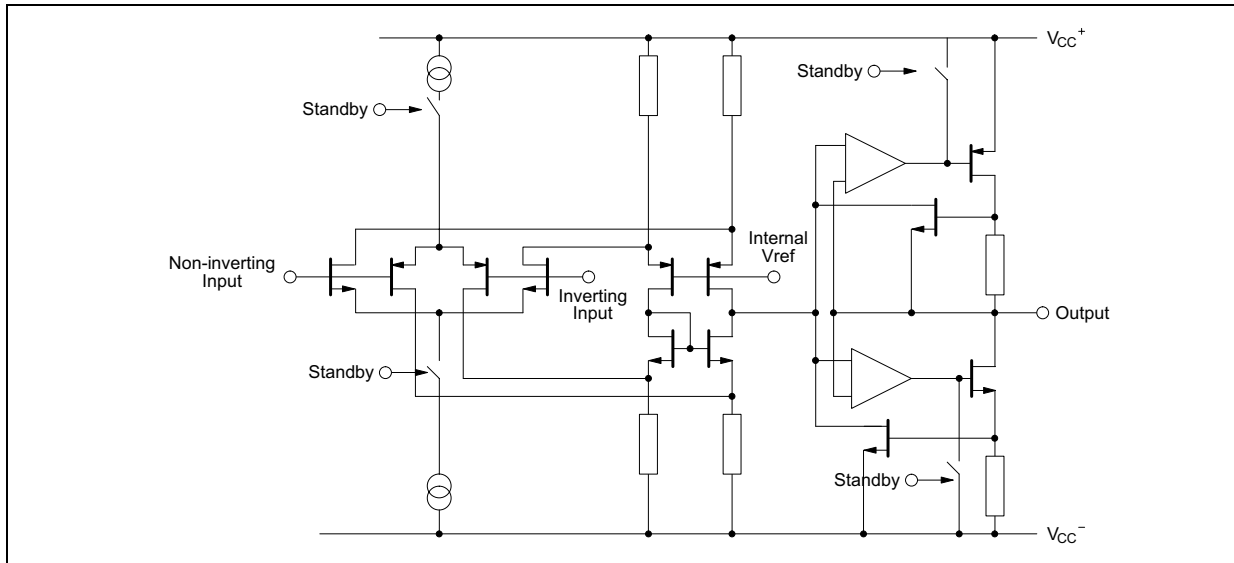
N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)



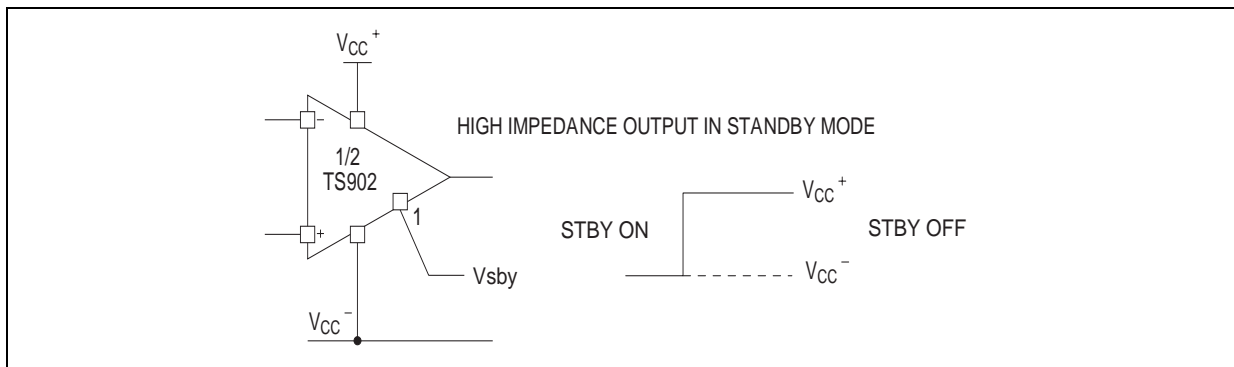
PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM (1/2 TS902)



STANDBY POSITION



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ¹⁾	18	V
V_{id}	Differential Input Voltage ²⁾	± 18	V
V_i	Input Voltage ³⁾	-0.3 to 18	V
I_{in}	Current on Inputs	± 50	mA
I_o	Current on Outputs	± 130	mA
T_{oper}	Operating Free Air Temperature Range TS902I	-40 to + 125	$^{\circ}C$
T_{stg}	Storage Temperature	-65 to +150	$^{\circ}C$

1. All voltages values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are non-inverting input terminal with respect to the inverting input terminal.
3. The magnitude of input and output voltages must never exceed $V_{CC}^{+} + 0.3V$.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	2.7 to 16	V
V_{icm}	Common Mode Input Voltage Range	$V_{CC}^{-} - 0.2$ to $V_{CC}^{+} + 0.2$	V

ELECTRICAL CHARACTERISTICS
 $V_{CC}^+ = 10V$, $V_{CC}^- = 0V$, R_L , C_L connected to $V_{CC/2}$, Standby OFF, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($V_{ic} = V_o = V_{CC/2}$) $T_{min.} \leq T_{amb} \leq T_{max.}$			10 12	mV
ΔV_{io}	Input Offset Voltage Drift		5		$\mu V/^\circ C$
I_{io}	Input Offset Current ¹⁾ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	100 200	pA
I_{ib}	Input Bias Current ¹⁾ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	150 300	pA
I_{CC}	Supply Current (per amplifier, $A_{VCL} = 1$, no load) $T_{min.} \leq T_{amb} \leq T_{max.}$		400	600 700	μA
CMR	Common Mode Rejection Ratio $V_{ic} = 3$ to $7V$, $V_o = 5V$ $V_{ic} = 0$ to $10V$, $V_o = 5V$		90 75		dB
SVR	Supply Voltage Rejection Ratio ($V_{CC}^+ = 5$ to $10V$, $V_o = V_{CC/2}$)		90		dB
A_{vd}	Large Signal Voltage Gain ($R_L = 10k\Omega$, $V_o = 2.5V$ to $7.5V$) $T_{min.} \leq T_{amb} \leq T_{max.}$	15 10	60		V/mV
V_{OH}	High Level Output Voltage ($V_{id} = 1V$) $T_{min.} \leq T_{amb} \leq T_{max.}$	$R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$	9.85 9 9.35 7.8 9.8 9		V
V_{OL}	Low Level Output Voltage ($V_{id} = -1V$) $T_{min.} \leq T_{amb} \leq T_{max.}$	$R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$		50 650 2300 150 900	mV
I_o	Output Short Circuit Current ($V_{id} = \pm 1V$) Source ($V_o = V_{CC}$) Sink ($V_o = V_{CC}^+$)		60 60		mA
GBP	Gain Bandwidth Product ($A_{VCL} = 100$, $R_L = 10k\Omega$, $C_L = 100pF$, $f = 100kHz$)		1.4		MHz
SR	Slew Rate ($A_{VCL} = 1$, $R_L = 10k\Omega$, $C_L = 100pF$, $V_i = 2.5V$ to $7.5V$)		1		V/ μs
ϕ_m	Phase Margin		40		Degrees
en	Equivalent Input Noise Voltage ($R_s = 100\Omega$, $f = 1kHz$)		30		nV/ \sqrt{Hz}
THD	Total Harmonic Distortion ($A_{VCL} = 1$, $R_L = 10k\Omega$, $C_L = 100pF$, $V_o = 4.75V$ to $5.25V$, $f = 1kHz$)		0.02		%
C_{in}	Input Capacitance		1.5		pF
V_{O1}/V_{O2}	Channel Separation ($f = 1kHz$)		120		dB

1. Maximum values including unavoidable inaccuracies of the industrial test

STANDBY MODE
 $V_{CC}^+ = 10V$, $V_{CC}^- = 0V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{inSBY/ON}$	Pin 1 Threshold Voltage for STANDBY ON		8.2		V
$V_{inSBY/OFF}$	Pin 1 Threshold Voltage for STANDBY OFF		8.5		V
$I_{CC SBY}$	Total Consumption in Standby Position (STANDBY ON)		1		μA

TYPICAL CHARACTERISTICS

Figure 1a : Supply Current (each amplifier) vs Supply Voltage

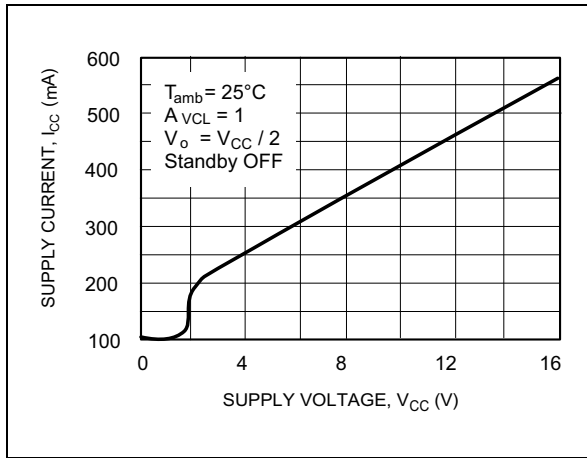


Figure 1b : Supply Current (each amplifier) vs Supply Voltage (in STANDBY mode)

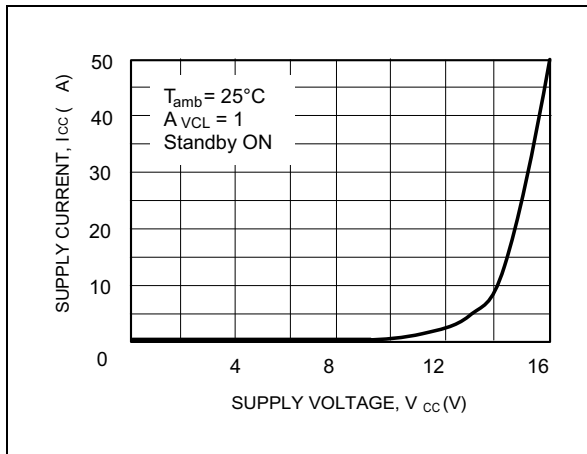


Figure 2 : Input Bias Current vs Temperature

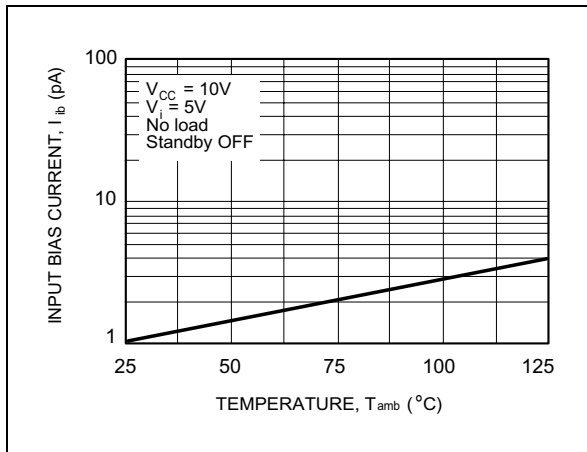


Figure 3a : High Level Output Voltage vs High Level Output Current

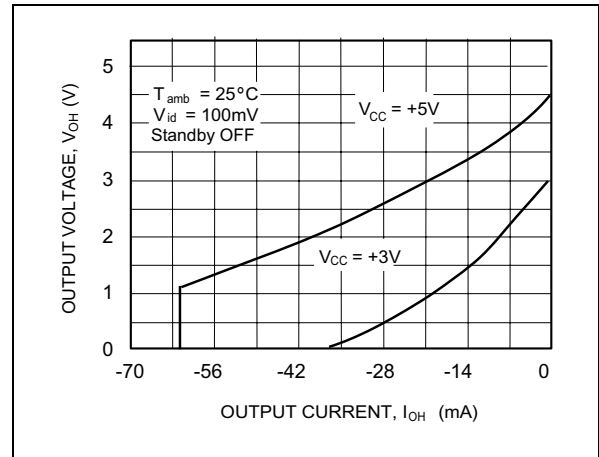


Figure 3b : High Level Output Voltage vs High Level Output Current

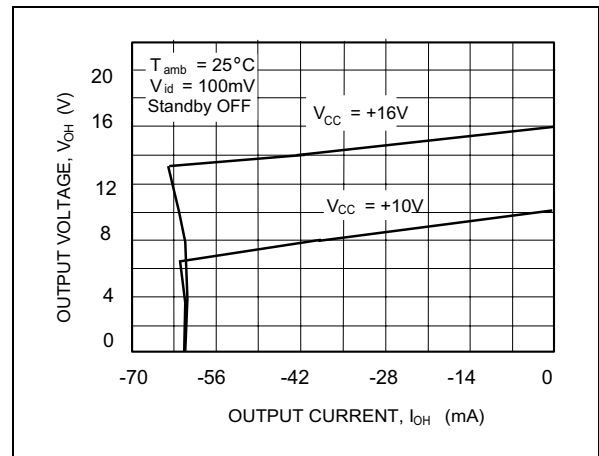


Figure 4a : Low Level Output Voltage vs Low Level Output Current

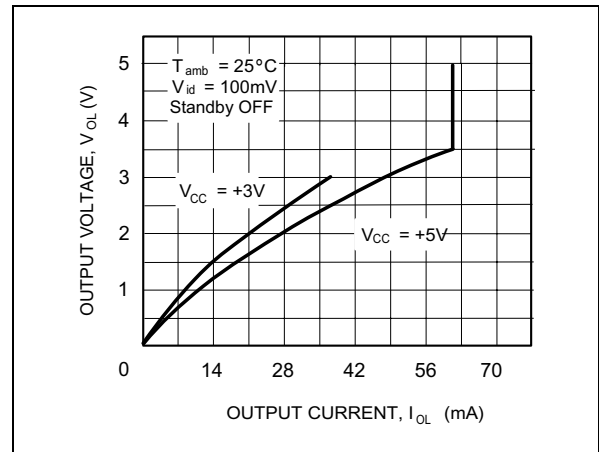


Figure 4b : Low Level Output Voltage vs Low Level Output Current

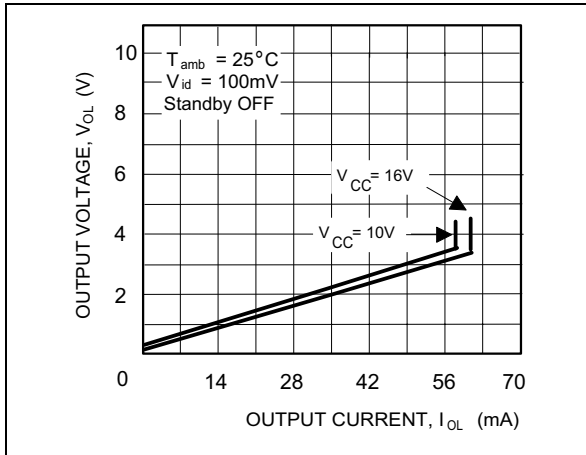


Figure 6a : Gain Bandwidth Product vs Supply Voltage

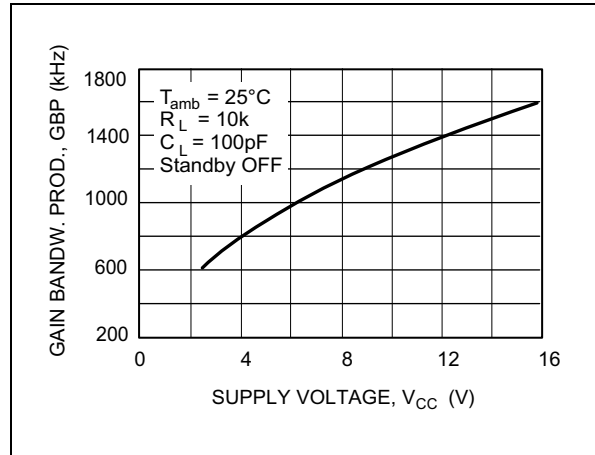


Figure 5a : Gain and Phase vs Frequency

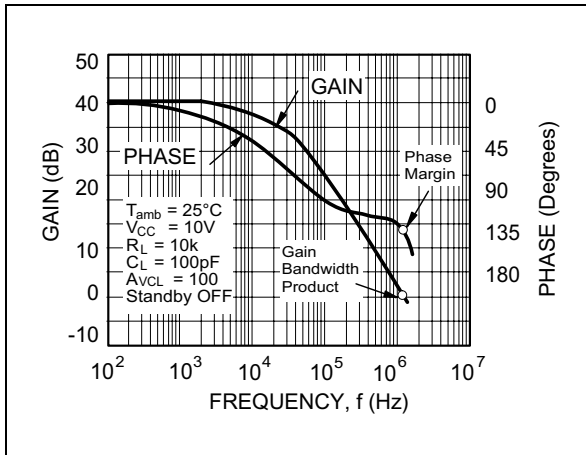


Figure 6b : Gain Bandwidth Product vs Supply Voltage

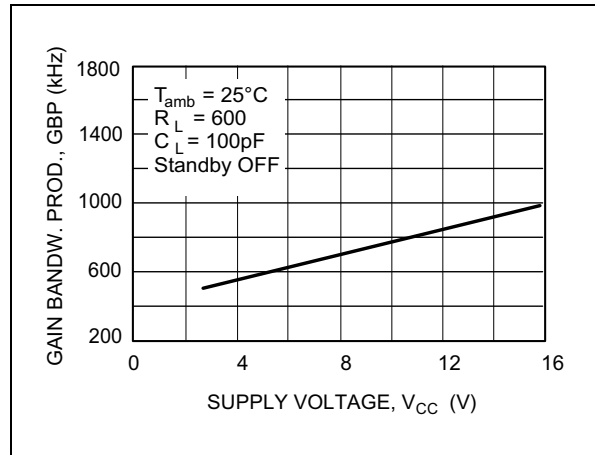


Figure 5b : Gain and Phase vs Frequency

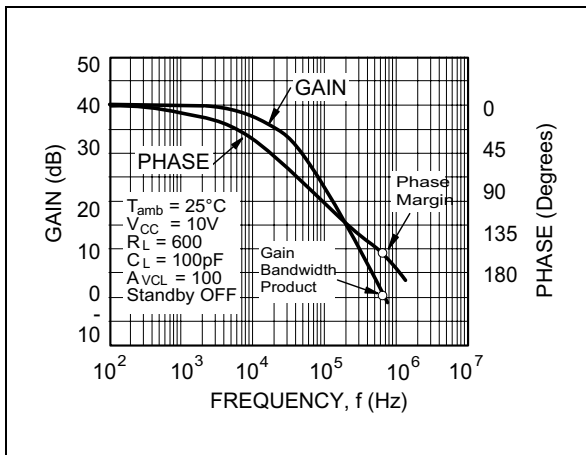


Figure 7a : Phase Margin vs Supply Voltage

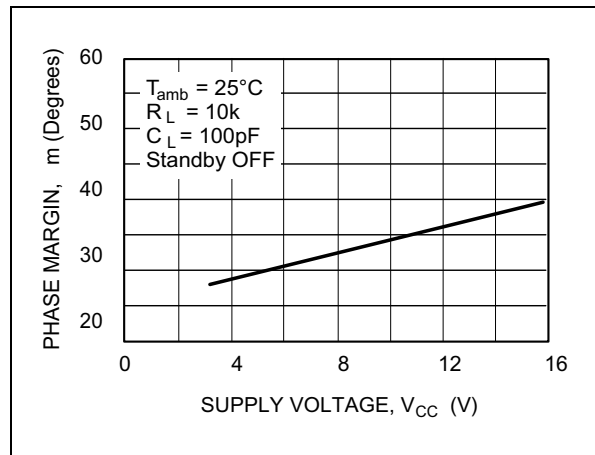


Figure 7b : Phase Margin vs Supply Voltage

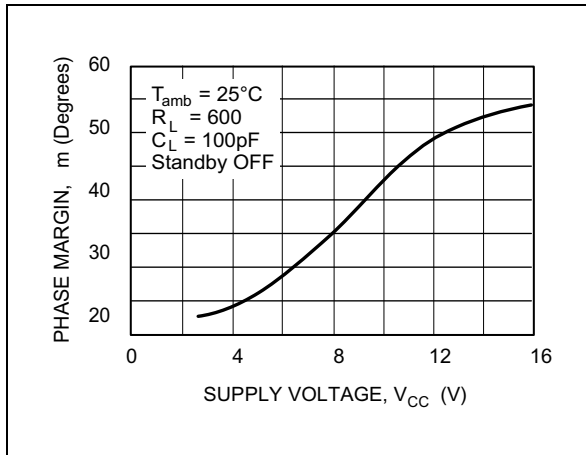
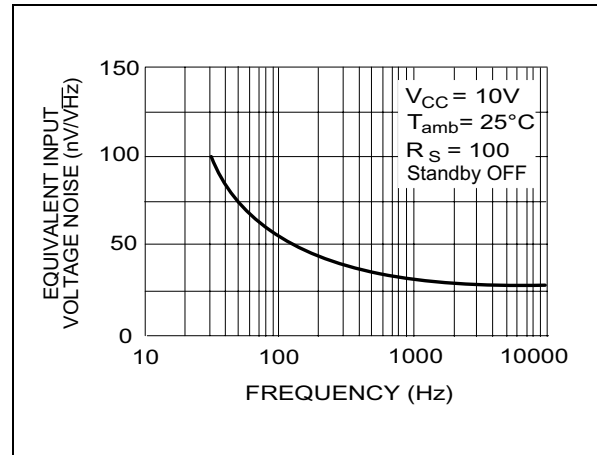


Figure 8 : Input Voltage Noise vs Frequency



STANDBY APPLICATION

The two operators of the TS902 are **both** put on **STANDBY**.

In this configuration (standby ON) :

- The **total consumption** of the circuit is considerably reduced down to 0.5 μ A ($V_{CC} = 3V$). This standby consumption vs V_{CC} curve is given figure 1b.
- The **both outputs** are in **high impedance** state. No output current can then be sourced or sunk by the device.

The standby pin 1 should never stay unconnected.

- The “**standby OFF**” state, is reached when the pin 1 voltage is **higher than $V_{in\ SBY/OFF}$** .
- The “**standby ON**” state is assured by a pin 1 voltage **lower than $V_{in\ SBY/ON}$** . (see electrical characteristics)

MACROMODELS

Applies to : TS902I

** Standard Linear Ics Macromodels, 1993.

** CONNECTIONS :

- * 1 INVERTING INPUT
- * 2 NON-INVERTING INPUT
- * 3 OUTPUT
- * 4 POSITIVE POWER SUPPLY
- * 5 NEGATIVE POWER SUPPLY
- * 6 STANDBY

.SUBCKT TS902 1 3 2 4 5 6 (analog)

.MODEL MDTH D IS=1E-8 KF=6.563355E-14 CJO=10F

* INPUT STAGE

CIP 2 5 1.500000E-12

CIN 1 5 1.500000E-12

EIP 10 0 2 0 1

EIN 16 0 1 0 1

RIP 10 11 6.500000E+00

RIN 15 16 6.500000E+00

RIS 11 15 7.655100E+00

DIP 11 12 MDTH 400E-12

DIN 15 14 MDTH 400E-12

VOFP 12 13 DC 0.000000E+00

VOFN 13 14 DC 0

FPOL 13 0 VSTB 1

CPS 11 15 3.82E-08

DINN 17 13 MDTH 400E-12

VIN 17 5 -0.5000000E+00

DINR 15 18 MDTH 400E-12

VIP 4 18 -0.5000000E+00

FCP 4 5 VOFP 8.6E+00

FCN 5 4 VOFN 8.6E+00

ISTB0 5 4 900NA

* AMPLIFYING STAGE

FIP 0 19 VOFP 5.500000E+02

FIN 0 19 VOFN 5.500000E+02

RG1 19 120 5.087344E+05

GCOM1 120 5 POLY(1) 110 109 LEVEL=1 6.25E+11

RG2 121 19 5.087344E+05

GCOM2 121 4 POLY(1) 110 109 LEVEL=1 6.25E+11

CC 19 29 2.200000E-08

HZTP 30 29 VOFP 12.33E+02

HZTN 5 30 VOFN 12.33E+02

DOPM 19 22 MDTH 400E-12

DONM 21 19 MDTH 400E-12

HOPM 22 28 VOUT 3135

VIPM 28 4 150

HONM 21 27 VOUT 3135

VINM 5 27 150

EOUT 26 23 19 5 1

VOUT 23 5 0

ROUT 26 103 65

COUT 103 5 1.000000E-12

GCOM 103 3 POLY(1) 110 109 LEVEL=1 6.25E+11

* OUTPUT SWING

DOP 19 68 MDTH 400E-12

VOP 4 25 1.924

HSCP 68 25 VSCP1 1E8

DON 69 19 MDTH 400E-12

VON 24 5 2.4419107

HSCN 24 69 VSCN1 1.5E8

VSCTHP 60 61 0.1375

DSCP1 61 63 MDTH 400E-12

VSCP1 63 64 0

ISCP 64 0 1.000000E-8

DSCP2 0 64 MDTH 400E-12

DSCN2 0 74 MDTH 400E-12

ISCN 74 0 1.000000E-8

VSCN1 73 74 0

DSCN1 71 73 MDTH 400E-12

VSCTHN 71 70 -0.75

ESCP 60 0 2 1 500

ESCN 70 0 2 1 -2000

* STANDBY

RM1 4 111 1E+12

RM2 5 111 1E+12

RSTBIN 6 0 1E+12

ESTBIN 106 0 6 0 1

ESTBREF 106 107 111 0 1

DSTB1 107 108 MDTH 400E-12

VSTB 108 109 0

ISTB 109 0 40U

RSTB 109 110 1

DSTB2 0 110 MDTH 400E-12

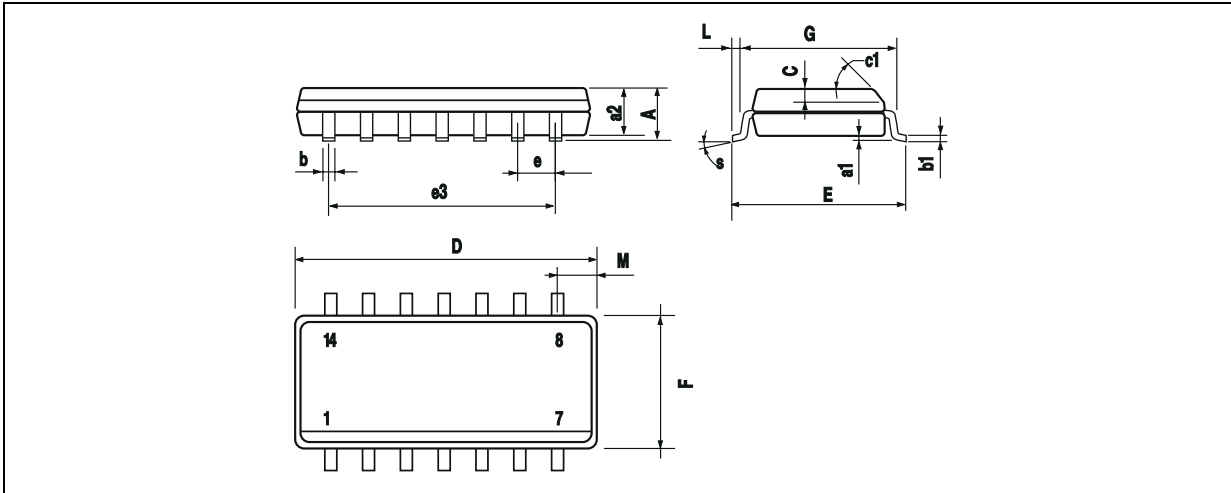
.ENDS

ELECTRICAL CHARACTERISTICS

V_{CC+} = 5V, V_{CC-} = 0V, R_L, C_L connected to V_{CC/2}, Standby OFF, T_{amb} = 25°C (unless otherwise specified)

Symbol	Conditions	Value	Unit
V _{io}		0	mV
A _{vd}	R _L = 10kΩ	30	V/mV
I _{CC}	No load, per operator	230	μA
V _{icm}		-0.2 to 5.2	V
V _{OH}	R _L = 10kΩ	4.95	V
V _{OL}	R _L = 10kΩ	50	mV
I _{sink}	V _O = 10V	60	mA
I _{source}	V _O = 0V	60	mA
GBP	R _L = 10kΩ, C _L = 100pF	0.8	MHz
SR	R _L = 10kΩ, C _L = 100pF	0.8	V/μs
φ _m	R _L = 10kΩ, C _L = 100pF	30	Degrees
I _{CC STBY}	V _{STBY} = 0V	500	nA

PACKAGE MECHANICAL DATA
 14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D (1)	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F (1)	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

Note : (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

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